

PE3335

**3000 MHz UltraCMOS™ Integer-N PLL
for Low Phase Noise Applications**

Product Description

Peregrine's PE3335 is a high performance integer-N PLL capable of frequency synthesis up to 3000 MHz. The superior phase noise performance of the PE3335 makes it ideal for applications such as LMDS / MMDS / WLL basestations and demanding terrestrial systems.

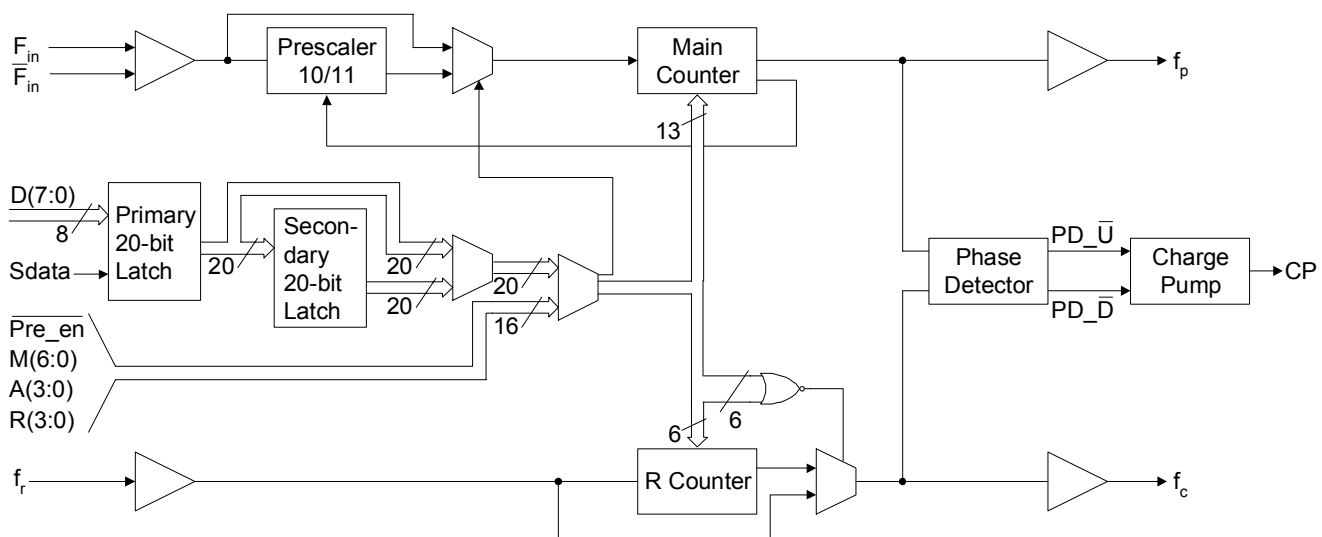
The PE3335 features a 10/11 dual modulus prescaler, counters, phase comparator and a charge pump as shown in Figure 1. Counter values are programmable through either a serial or parallel interface and can also be directly hard wired.

The PE3335 Phase Locked-Loop is optimized for terrestrial applications. It is manufactured on Peregrine's UltraCMOS™ process, a patented variation of silicon-on-insulator (SOI) technology on a sapphire substrate, offering the performance of GaAs with the economy and integration of conventional CMOS.

Features

- 3000 MHz operation
- $\div 10/11$ dual modulus prescaler
- Internal phase detector with charge pump
- Serial, parallel or hardwired programmable
- Ultra-low phase noise
- Available in 44-lead PLCC and 7x7 mm 48-lead QFN packages

Figure 1. Block Diagram



The image displays two pin configuration diagrams for the ADXL345 digital accelerometer. The left diagram shows the 44-lead PLCC package, and the right diagram shows the 48-lead QFN package. Both diagrams include pin numbers, pin symbols, and the corresponding signal or power name.

44-lead PLCC Pin Configuration:

- Top Row (Pins 6-40):** 6: GND, 7: D_0, M_0 , 8: D_1, M_1 , 9: D_2, M_2 , 10: D_3, M_3 , 11: V_{DD} , 12: V_{DD} , 13: S_WR, D_4, M_4 , 14: $Sdata, D_5, M_5$, 15: $Sclk, D_6, M_6$, 16: $FSELS, D_7, Pre_en$, 17: GND, 18: F_n , 19: E_WR, A_1 , 20: $M2_WR, A_2$, 21: $Smode, A_3$, 22: $Bmode$, 23: V_{DD} , 24: $M1_WR$, 25: A_WR , 26: Hop_WR , 27: F_n , 28: F_n .
- Bottom Row (Pins 39-40):** 39: f_c , 40: GND.
- Right Side (Pins 41-44):** 41: GND, 42: f_r , 43: LD, 44: \overline{Enh} .
- Left Side (Pins 1-5):** 1: V_{DD} , 2: R_0 , 3: R_1 , 4: R_2 , 5: R_3 .

48-lead QFN Pin Configuration:

- Top Row (Pins 48-37):** 48: GND, 47: R_3 , 46: R_2 , 45: R_1 , 44: R_0 , 43: V_{DD} , 42: \overline{Enh} , 41: LD, 40: f_r , 39: GND, 38: GND, 37: GND.
- Bottom Row (Pins 13-24):** 13: E_WR, A_1 , 14: $M2_WR, A_2$, 15: $Smode, A_3$, 16: $Bmode$, 17: V_{DD} , 18: V_{DD} , 19: $M1_WR$, 20: A_WR , 21: Hop_WR , 22: F_n , 23: F_n , 24: GND.
- Left Side (Pins 36-31):** 36: f_c , 35: V_{DD-f_c} , 34: NC, 33: NC, 32: CP, 31: V_{DD} .
- Right Side (Pins 30-25):** 30: V_{DD} , 29: C_{ext} , 28: V_{DD} , 27: D_{out} , 26: V_{DD-f_p} , 25: f_p .
- Internal Connections (Pins 7-12):** 7: S_WR, D_4, M_4 , 8: D_1, M_1 , 9: D_2, M_2 , 10: $FSELS, D_7, Pre_en$, 11: GND, 12: V_{DD} .

Pin No. (44-lead PLCC)	Pin No. (48-lead QFN)	Pin Name	Interface Mode	Type	Description
1	43	V _{DD}	ALL	(Note 1)	Power supply input. Input may range from 2.85 V to 3.15 V. Bypassing recommended.
2	44	R ₀	Direct	Input	R Counter bit0 (LSB).
3	45	R ₁	Direct	Input	R Counter bit1.
4	46	R ₂	Direct	Input	R Counter bit2.
5	47	R ₃	Direct	Input	R Counter bit3.
6	48	GND	ALL	(Note 1)	Ground.
7	1	D ₀	Parallel	Input	Parallel data bus bit0 (LSB).
		M ₀	Direct	Input	M Counter bit0 (LSB).
8	2	D ₁	Parallel	Input	Parallel data bus bit1.
		M ₁	Direct	Input	M Counter bit1.
9	3	D ₂	Parallel	Input	Parallel data bus bit2.
		M ₂	Direct	Input	M Counter bit2.
10	4	D ₃	Parallel	Input	Parallel data bus bit3.
		M ₃	Direct	Input	M Counter bit3.
11	5	V _{DD}	ALL	(Note 1)	Same as pin 1 (QFN48 pin 43).
12	6	V _{DD}	ALL	(Note 1)	Same as pin 1 (QFN48 pin 43).

Table 1. Pin Descriptions (continued)

Pin No. (44-lead PLCC)	Pin No. (48-lead QFN)	Pin Name	Interface Mode	Type	Description
13	7	S_WR	Serial	Input	Serial load enable input. While S_WR is "low", Sdata can be serially clocked. Primary register data are transferred to the secondary register on S_WR or Hop_WR rising edge.
		D ₄	Parallel	Input	Parallel data bus bit4
		M ₄	Direct	Input	M Counter bit4
14	8	Sdata	Serial	Input	Binary serial data input. Input data entered MSB first.
		D ₅	Parallel	Input	Parallel data bus bit5.
		M ₅	Direct	Input	M Counter bit5.
15	9	Sclk	Serial	Input	Serial clock input. Sdata is clocked serially into the 20-bit primary register (E_WR "low") or the 8-bit enhancement register (E_WR "high") on the rising edge of Sclk.
		D ₆	Parallel	Input	Parallel data bus bit6.
		M ₆	Direct	Input	M Counter bit6.
16	10	FSELS	Serial	Input	Selects contents of primary register (FSELS=1) or secondary register (FSELS=0) for programming of internal counters while in Serial Interface Mode.
		D ₇	Parallel	Input	Parallel data bus bit7 (MSB).
		Pre_en	Direct	Input	Prescaler enable, active "low". When "high", F _{in} bypasses the prescaler.
17	11	GND	ALL		Ground.
18	12	FSELP	Parallel	Input	Selects contents of primary register (FSELP=1) or secondary register (FSELP=0) for programming of internal counters while in Parallel Interface Mode.
		A ₀	Direct	Input	A Counter bit0 (LSB).
19	13	E_WR	Serial	Input	Enhancement register write enable. While E_WR is "high", Sdata can be serially clocked into the enhancement register on the rising edge of Sclk.
			Parallel	Input	Enhancement register write. D[7:0] are latched into the enhancement register on the rising edge of E_WR.
		A ₁	Direct	Input	A Counter bit1.
20	14	M2_WR	Parallel	Input	M2 write. D[3:0] are latched into the primary register (R[5:4], M[8:7]) on the rising edge of M2_WR.
		A ₂	Direct	Input	A Counter bit2.
21	15	Smode	Serial, Parallel	Input	Selects serial bus interface mode (Bmode=0, Smode=1) or Parallel Interface Mode (Bmode=0, Smode=0).
		A ₃	Direct	Input	A Counter bit3 (MSB).
22	16	Bmode	ALL	Input	Selects direct interface mode (Bmode=1).
23	17,18	V _{DD}	ALL	(Note 1)	Same as pin 1 (MLP48 pin 43).
24	19	M1_WR	Parallel	Input	M1 write. D[7:0] are latched into the primary register (Pre_en, M[6:0]) on the rising edge of M1_WR.
25	20	A_WR	Parallel	Input	A write. D[7:0] are latched into the primary register (R[3:0], A[3:0]) on the rising edge of A_WR.
26	21	Hop_WR	Serial, Parallel	Input	Hop write. The contents of the primary register are latched into the secondary register on the rising edge of Hop_WR.
27	22	F _{in}	ALL	Input	Prescaler input from the VCO. 3.0 GHz max frequency.

Table 1. Pin Descriptions (continued)

Pin No. (44-lead PLCC)	Pin No. (48-lead QFN)	Pin Name	Interface Mode	Type	Description
28	23	$\overline{F_{in}}$	ALL	Input	Prescaler complementary input. A bypass capacitor should be placed as close as possible to this pin and be connected in series with a 50 Ω resistor directly to the ground plane.
29	24	GND	ALL		Ground.
30	25	f_p	ALL	Output	Monitor pin for main divider output. Switching activity can be disabled through enhancement register programming or by floating or grounding V_{DD} pin 31.
31	26	$V_{DD}-f_p$	ALL	(Note 1)	V_{DD} for f_p . Can be left floating or connected to GND to disable the f_p output.
32	27	Dout	Serial, Parallel	Output	Data Out. The MSEL signal and the raw prescaler output are available on Dout through enhancement register programming.
33	28	V_{DD}	ALL	(Note 1)	Same as pin 1 (QFN48 pin 43).
34	29	Cext	ALL	Output	Logical "NAND" of PD_U and PD_D terminated through an on chip, 2 k Ω series resistor. Connecting Cext to an external capacitor will low pass filter the input to the inverting amplifier used for driving LD.
35	30	V_{DD}	ALL	(Note 1)	Same as pin 1 (QFN48 pin 43).
36	32	CP	ALL	Output	Charge pump current is sourced when f_c leads f_p and sinked when f_c lags f_p .
37	33, 34	NC	ALL		No connection.
38	35	$V_{DD}-f_c$	ALL	(Note 1)	V_{DD} for f_c can be left floating or connected to GND to disable the f_c output.
39	36	f_c	ALL	Output	Monitor pin for reference divider output. Switching activity can be disabled through enhancement register programming or by floating or grounding V_{DD} pin 38.
40	31,37	GND	ALL		Ground.
41	38,39	GND	ALL		Ground.
42	40	f_r	ALL	Input	Reference frequency input.
43	41	LD	ALL	Output	Lock detect and open drain logical inversion of Cext. When the loop is in lock, LD is high impedance, otherwise LD is a logic low ("0").
44	42	\overline{Enh}	Serial, Parallel	Input	Enhancement mode. When asserted low ("0"), enhancement register bits are functional.

Note 1: All V_{DD} pins are connected by diodes and must be supplied with the same positive voltage level.

$V_{DD}-f_p$ and $V_{DD}-f_c$ are used to power the f_p and f_c outputs and can alternatively be left floating or connected to GND to disable the f_p and f_c outputs.

Note 2: All digital input pins have 70 k Ω pull-down resistors to ground.

Table 2. Absolute Maximum Ratings

Symbol	Parameter/Conditions	Min	Max	Units
V_{DD}	Supply voltage	-0.3	4.0	V
V_I	Voltage on any input	-0.3	$V_{DD} + 0.3$	V
I_I	DC into any input	-10	+10	mA
I_O	DC into any output	-10	+10	mA
T_{stg}	Storage temperature range	-65	150	°C

Table 3. Operating Ratings

Symbol	Parameter/Conditions	Min	Max	Units
V_{DD}	Supply voltage	2.85	3.15	V
T_A	Operating ambient temperature range	-40	85	°C

Table 4. ESD Ratings

Symbol	Parameter/Conditions	Level	Units
V_{ESD}	ESD voltage (Human Body)	1000	V

Note 1: Periodically sampled, not 100% tested. Tested per MIL-STD-883, M3015 C2

Electrostatic Discharge (ESD) Precautions

When handling this UltraCMOS™ device, observe the same precautions that you would use with other ESD-sensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the specified rating in Table 4.

Latch-Up Avoidance

Unlike conventional CMOS devices, UltraCMOS™ devices are immune to latch-up.

Table 5. DC Characteristics: $V_{DD} = 3.0\text{ V}$, $-40^\circ\text{ C} < T_A < 85^\circ\text{ C}$, unless otherwise specified

Symbol	Parameter	Conditions	Min	Typ	Max	Units
I_{DD}	Operational supply current; Prescaler disabled Prescaler enabled	$V_{DD} = 2.85\text{ to }3.15\text{ V}$		10 24	31	mA mA
Digital Inputs: All except f_i , R_0 , F_{in} , F_{in}						
V_{IH}	High level input voltage	$V_{DD} = 2.85\text{ to }3.15\text{ V}$	$0.7 \times V_{DD}$			V
V_{IL}	Low level input voltage	$V_{DD} = 2.85\text{ to }3.15\text{ V}$			$0.3 \times V_{DD}$	V
I_{IH}	High level input current	$V_{IH} = V_{DD} = 3.15\text{ V}$			+70	μA
I_{IL}	Low level input current	$V_{IL} = 0$, $V_{DD} = 3.15\text{ V}$	-1			μA
Reference Divider input: f_i						
I_{IHR}	High level input current	$V_{IH} = V_{DD} = 3.15\text{ V}$			+100	μA
I_{ILR}	Low level input current	$V_{IL} = 0$, $V_{DD} = 3.15\text{ V}$	-100			μA
R0 Input (Pull-up Resistor): R_0						
I_{IHRO}	High level input current	$V_{IH} = V_{DD} = 3.15\text{ V}$			+5	μA
I_{ILRO}	Low level input current	$V_{IL} = 0$, $V_{DD} = 3.15\text{ V}$	-5			μA
Counter output D_{out}						
V_{OLD}	Output voltage LOW	$I_{out} = 6\text{ mA}$			0.4	V
V_{OHD}	Output voltage HIGH	$I_{out} = -3\text{ mA}$	$V_{DD} - 0.4$			V
Lock detect outputs: C_{ext} , LD						
V_{OLC}	Output voltage LOW, C_{ext}	$I_{out} = 100\text{ mA}$			0.4	V
V_{OHC}	Output voltage HIGH, C_{ext}	$I_{out} = -100\text{ mA}$	$V_{DD} - 0.4$			V
V_{OLLD}	Output voltage LOW, LD	$I_{out} = 6\text{ mA}$			0.4	V
Charge Pump output: CP						
$I_{CP} - \text{Source}$	Drive current	$V_{CP} = V_{DD} / 2$	-2.6	-2	-1.4	mA
$I_{CP} - \text{Sink}$	Drive current	$V_{CP} = V_{DD} / 2$	1.4	2	2.6	mA
I_{CPL}	Leakage current	$1.0\text{ V} < V_{CP} < V_{DD} - 1.0\text{ V}$	-1	1		μA
$I_{CP} - \text{Source vs. } I_{CP} \text{ Sink}$	Sink vs. source mismatch	$V_{CP} = V_{DD} / 2$, $T_A = 25^\circ\text{ C}$			15	%
$I_{CP} \text{ vs. } V_{CP}$	Output current magnitude variation vs. voltage	$V < V_{CP} < V_{DD} - 1.0\text{ V}$, $T_A = 25^\circ\text{ C}$			15	%

Table 6. AC Characteristics: $V_{DD} = 3.0\text{ V}$, $-40^{\circ}\text{ C} < T_A < 85^{\circ}\text{ C}$, unless otherwise specified

Symbol	Parameter	Conditions	Min	Max	Units
Control Interface and Latches (see Figures 3, 4, 5)					
f_{Clk}	Serial data clock frequency			10	MHz
t_{ClkH}	Serial clock HIGH time		30		ns
t_{ClkL}	Serial clock LOW time		30		ns
t_{DSU}	Sdata set-up time after Sclk rising edge, D[7:0] set-up time to M1_WR, M2_WR, A_WR, E_WR rising edge		10		ns
t_{DHLD}	Sdata hold time after Sclk rising edge, D[7:0] hold time to M1_WR, M2_WR, A_WR, E_WR rising edge		10		ns
t_{PW}	S_WR, M1_WR, M2_WR, A_WR, E_WR pulse width		30		ns
t_{CWR}	Sclk rising edge to S_WR rising edge. S_WR, M1_WR, M2_WR, A_WR falling edge to Hop_WR rising edge		30		ns
t_{CE}	Sclk falling edge to E_WR transition		30		ns
t_{WRC}	S_WR falling edge to Sclk rising edge. Hop_WR falling edge to S_WR, M1_WR, M2_WR, A_WR rising edge		30		ns
t_{EC}	E_WR transition to Sclk rising edge		30		ns
t_{MDO}	MSEL data out delay after Fin rising edge	$C_L = 12\text{ pf}$		8	ns
Main Divider (Including Prescaler)					
F_{in}	Operating frequency		500	3000	MHz
P_{Fin}	Input level range	External AC coupling	-5	5	dBm
Main Divider (Prescaler Bypassed)					
F_{in}	Operating frequency		50	300	MHz
P_{Fin}	Input level range	External AC coupling	-5	5	dBm
Reference Divider					
f_r	Operating frequency	(Note 1)	(Note 2)	100	MHz
P_{fr}	Reference input power	Single ended input	-2	10	dBm
V_{fr}	Input sensitivity	External AC coupling (Note 3)	0.5		$V_{\text{p-p}}$
Phase Detector					
f_c	Comparison frequency	(Note 1)		20	MHz

Note 1: Parameter is guaranteed through characterization only and is not tested.

Note 2: Running at low frequencies ($< 10\text{ MHz}$ sinewave), the device will still be functional but may cause phase noise degradation. Inserting a low-noise amplifier to square up the edges is recommended at lower input frequencies.

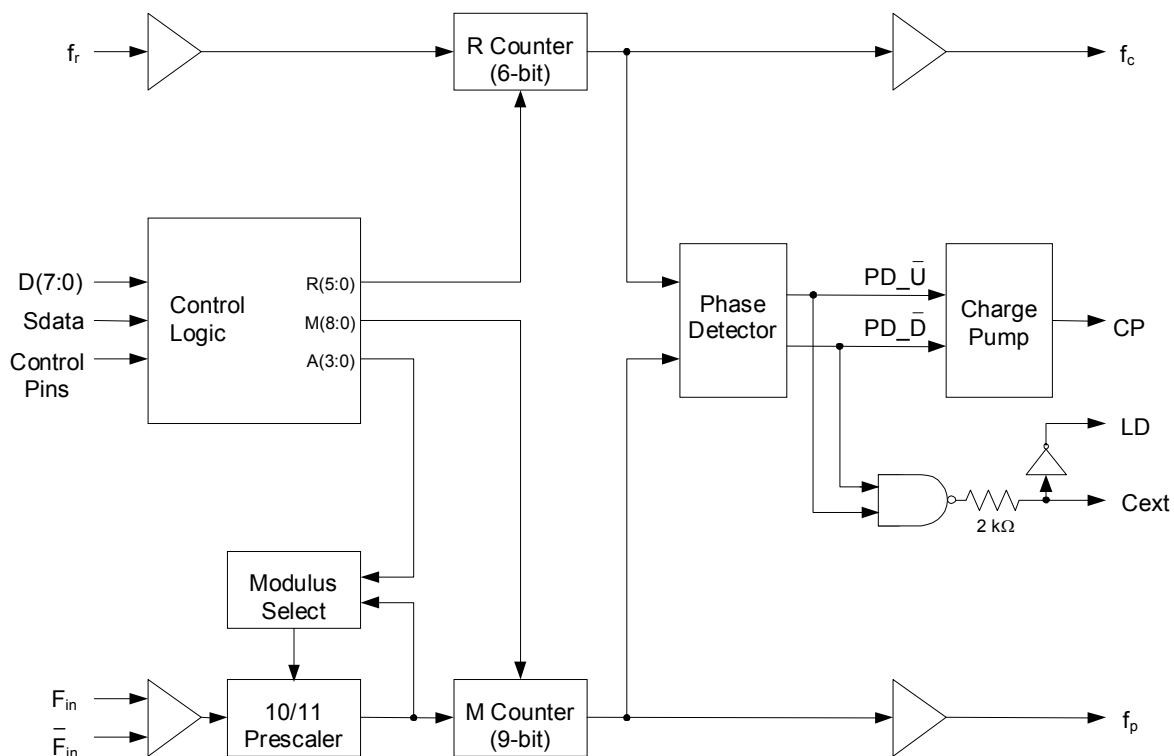
Note 3: CMOS logic levels may be used if DC coupled. For optimum phase noise performance, the reference input falling edge rate should be faster than 80 mV/ns .

Functional Description

The PE3335 consists of a prescaler, counters, a phase detector, a charge pump and control logic. The dual modulus prescaler divides the VCO frequency by either 10 or 11, depending on the value of the modulus select. Counters “R” and “M” divide the reference and prescaler output, respectively, by integer values stored in a 20-bit register. An additional counter (“A”) is used in the modulus select logic. The phase-frequency

detector generates up and down frequency control signals. The control logic includes a selectable chip interface. Data can be written via serial bus, parallel bus, or hardwired direct to the pins. There are also various operational and test modes and lock detect.

Figure 3. Functional Block Diagram



Main Counter Chain

The main counter chain divides the RF input frequency, F_{in} , by an integer derived from the user defined values in the “M” and “A” counters. It is composed of the 10/11 dual modulus prescaler, modulus select logic, and 9-bit M counter. Setting $\overline{Pre_en}$ “low” enables the 10/11 prescaler. Setting $\overline{Pre_en}$ “high” allows F_{in} to bypass the prescaler and powers down the prescaler.

The output from the main counter chain, f_p , is related to the VCO frequency, F_{in} , by the following equation:

$$f_p = F_{in} / [10 \times (M + 1) + A] \quad (1)$$

where $A \leq M + 1$, $1 \leq M \leq 511$

When the loop is locked, F_{in} is related to the reference frequency, f_r , by the following equation:

$$F_{in} = [10 \times (M + 1) + A] \times (f_r / (R+1)) \quad (2)$$

where $A \leq M + 1$, $1 \leq M \leq 511$

A consequence of the upper limit on A is that F_{in} must be greater than or equal to $90 \times (f_r / (R+1))$ to obtain contiguous channels. Programming the M Counter with the minimum value of “1” will result in a minimum M Counter divide ratio of “2”.

When the prescaler is bypassed, the equation becomes:

$$F_{in} = (M + 1) \times (f_r / (R+1)) \quad (3)$$

where $1 \leq M \leq 511$

In Direct Interface Mode, main counter inputs M_7 and M_8 are internally forced low.

Reference Counter

The reference counter chain divides the reference frequency, f_r , down to the phase detector comparison frequency, f_c .

The output frequency of the 6-bit R Counter is related to the reference frequency by the following equation:

$$f_c = f_r / (R + 1) \quad (4)$$

where $0 \leq R \leq 63$

Note that programming R equal to “0” will pass the reference frequency, f_r , directly to the phase detector.

In Direct Interface Mode, R Counter inputs R_4 and R_5 are internally forced low (“0”).

Register Programming

Parallel Interface Mode

Parallel Interface Mode is selected by setting the \overline{Bmode} input “low” and the \overline{Smode} input “low”.

Parallel input data, $D[7:0]$, are latched in a parallel fashion into one of three, 8-bit primary register sections on the rising edge of $M1_WR$, $M2_WR$, or A_WR per the mapping shown in Table 7 on page 10. The contents of the primary register are transferred into a secondary register on the rising edge of Hop_WR according to the timing diagram shown in Figure 4. Data are transferred to the counters as shown in Table 7 on page 10.

The secondary register acts as a buffer to allow rapid changes to the VCO frequency. This double buffering for “ping-pong” counter control is programmed via the \overline{FSELP} input. When \overline{FSELP} is “high”, the primary register contents set the counter inputs. When \overline{FSELP} is “low”, the secondary register contents are utilized.

Parallel input data, $D[7:0]$, are latched into the enhancement register on the rising edge of E_WR according to the timing diagram shown in Figure 4. This data provides control bits as shown in Table 8 on page 10 with bit functionality enabled by asserting the \overline{Enh} input “low”.

Serial Interface Mode

Serial Interface Mode is selected by setting the \overline{Bmode} input “low” and the \overline{Smode} input “high”.

While the E_WR input is “low” and the S_WR input is “low”, serial input data ($Sdata$ input), B_0 to B_{19} , are clocked serially into the primary register on the rising edge of $Sclk$, MSB (B_0) first. The contents from the primary register are transferred into the secondary register on the rising edge of either S_WR or Hop_WR according to the timing diagram shown in Figures 4-5. Data are transferred to the counters as shown in Table 7 on page 10.

The double buffering provided by the primary and secondary registers allows for “ping-pong” counter control using the \overline{FSELS} input. When \overline{FSELS} is “high”, the primary register contents set the counter inputs. When \overline{FSELS} is “low”, the secondary register contents are utilized.

While the E_WR input is “high” and the S_WR

input is “low”, serial input data (Sdata input), B₀ to B₇, are clocked serially into the enhancement register on the rising edge of Sclk, MSB (B₀) first. The enhancement register is double buffered to prevent inadvertent control changes during serial loading, with buffer capture of the serially entered data performed on the falling edge of E_WR according to the timing diagram shown in Figure 5. After the falling edge of E_WR, the data provide control bits as shown in Table 8 with bit functionality enabled by asserting the Enh input “low”.

Direct Interface Mode

Direct Interface Mode is selected by setting the Bmode input “high”.

Counter control bits are set directly at the pins as shown in Table 7. In Direct Interface Mode, main counter inputs M₇ and M₈, and R Counter inputs R₄ and R₅ are internally forced low (“0”).

Table 7. Primary Register Programming

Interface Mode	Enh	Bmode	Smode	R ₅	R ₄	M ₈	M ₇	Pre_en	M ₆	M ₅	M ₄	M ₃	M ₂	M ₁	M ₀	R ₃	R ₂	R ₁	R ₀	A ₃	A ₂	A ₁	A ₀
Parallel	1	0	0	M2_WR rising edge load				M1_WR rising edge load								A_WR rising edge load							
				D ₃	D ₂	D ₁	D ₀	D ₇	D ₆	D ₅	D ₄	D ₃	D ₂	D ₁	D ₀	D ₇	D ₆	D ₅	D ₄	D ₃	D ₂	D ₁	D ₀
Serial*	1	0	1	B ₀	B ₁	B ₂	B ₃	B ₄	B ₅	B ₆	B ₇	B ₈	B ₉	B ₁₀	B ₁₁	B ₁₂	B ₁₃	B ₁₄	B ₁₅	B ₁₆	B ₁₇	B ₁₈	B ₁₉
Direct	1	1	X	0	0	0	0	Pre_en	M ₆	M ₅	M ₄	M ₃	M ₂	M ₁	M ₀	R ₃	R ₂	R ₁	R ₀	A ₃	A ₂	A ₁	A ₀

*Serial data clocked serially on Sclk rising edge while E_WR “low” and captured in secondary register on S_WR rising edge.

↑
MSB (first in)

↑
(last in) LSB

Table 8. Enhancement Register Programming

Interface Mode	Enh	Bmode	Smode	Reserved	Reserved	Reserved	Power down	Counter load	MSEL output	Prescaler output	f _c , f _p OE
Parallel	0	X	0	E_WR rising edge load							
				D ₇	D ₆	D ₅	D ₄	D ₃	D ₂	D ₁	D ₀
Serial*	0	X	1	B ₀	B ₁	B ₂	B ₃	B ₄	B ₅	B ₆	B ₇

*Serial data clocked serially on Sclk rising edge while E_WR “high” and captured in the double buffer on E_WR falling edge.

↑
MSB (first in)

↑
(last in) LSB

Figure 4. Parallel Interface Mode Timing Diagram

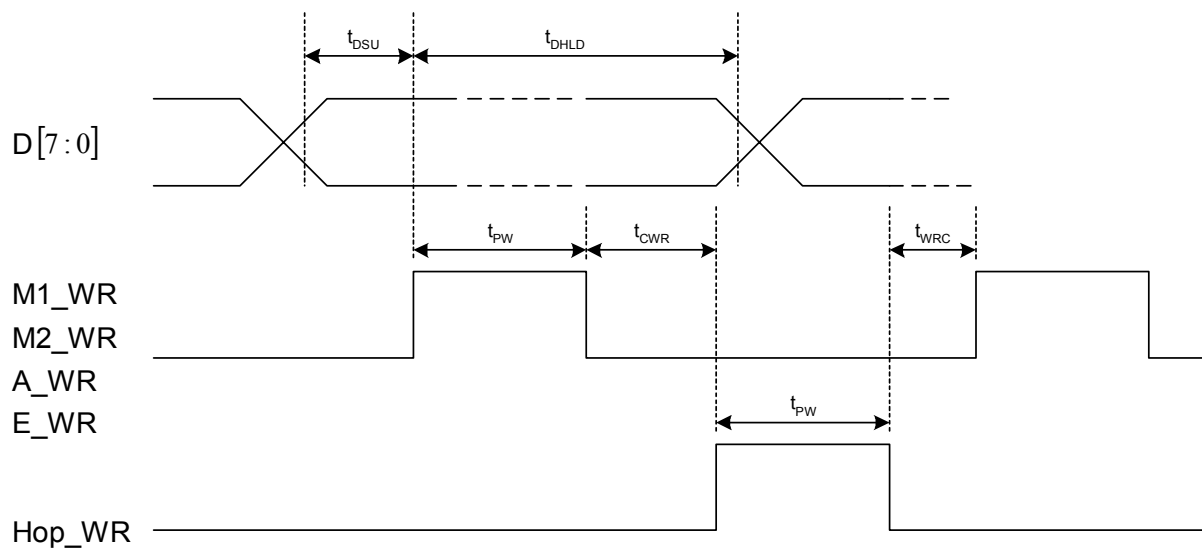
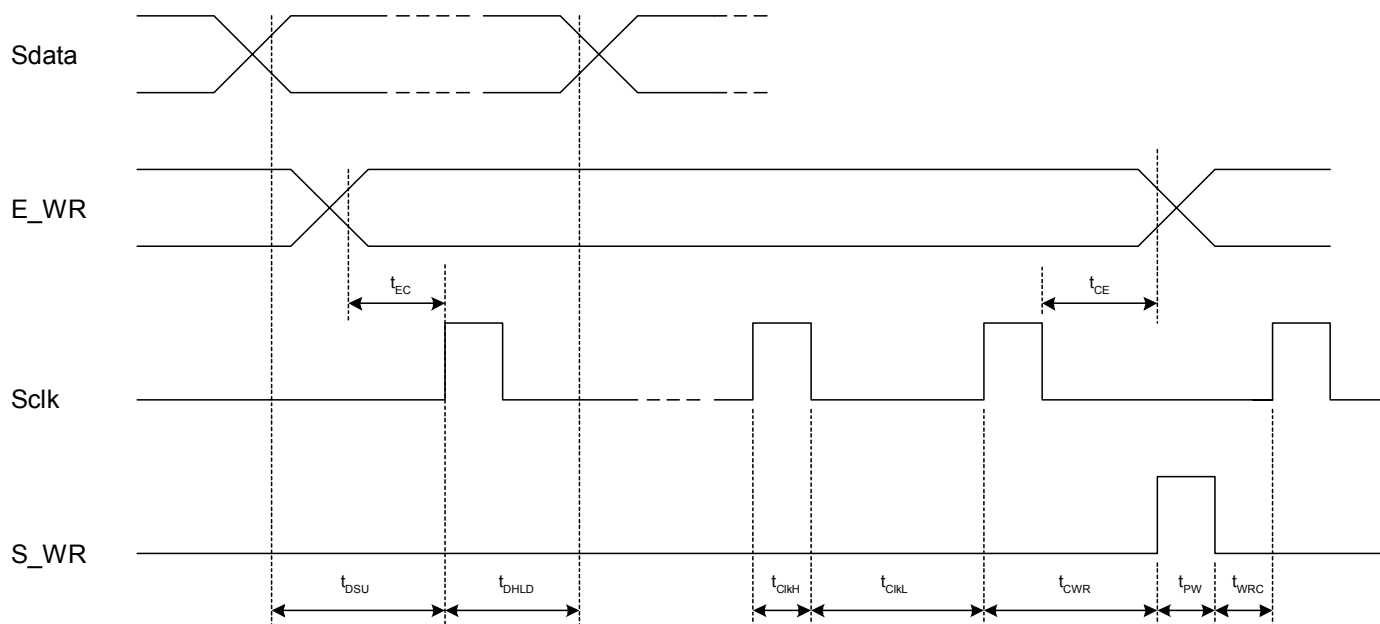


Figure 5. Serial Interface Mode Timing Diagram



Enhancement Register

The functions of the enhancement register bits are shown below with all bits active “high”.

Table 9. Enhancement Register Bit Functionality

Bit Function		Description
Bit 0	Reserved**	
Bit 1	Reserved**	
Bit 2	Reserved**	
Bit 3	Power down	Power down of all functions except programming interface.
Bit 4	Counter load	Immediate and continuous load of counter programming as directed by the Bmode and
Bit 5	MSEL output	Drives the internal dual modulus prescaler modulus select (MSEL) onto the Dout output.
Bit 6	Prescaler output	Drives the raw internal prescaler output onto the Dout output.
Bit 7	f_p , f_c OE	f_p , f_c outputs disabled.

** Program to 0

Phase Detector

The phase detector is triggered by rising edges from the main Counter (f_p) and the reference counter (f_c). It has two outputs, PD_U, and PD_D. If the divided VCO leads the divided reference in phase or frequency (f_p leads f_c), PD_D pulses “low”. If the divided reference leads the divided VCO in phase or frequency (f_c leads f_p), PD_U pulses “low”. The width of either pulse is directly proportional to phase offset between the two input signals, f_p and f_c .

The signals from the phase detector couple directly to a charge pump. PD_U controls a current source at pin CP with constant amplitude and pulse duration approximately the same as PD_U. PD_D similarly drives a current sink at pin

CP. The current pulses from pin CP are low pass filtered externally and then connected to the VCO tune voltage. PD_U pulses result in a current source, which increases the VCO frequency; PD_D pulses result in a current sink, which decreases VCO frequency (for a positive Kv VCO).

A lock detect output, LD is also provided, via the pin Cext. Cext is the logical “NAND” of PD_U and PD_D waveforms, which is driven through a series 2 kohm resistor. Connecting Cext to an external shunt capacitor provides low pass filtering of this signal. Cext also drives the input of an internal inverting comparator with an open drain output. Thus LD is an “AND” function of PD_U and PD_D.

Handling Requirements

All surface mount products which do not meet Level 1 moisture sensitivity requirements are processed through dry bake and pack procedure. The necessary data is recorded on the caution label of each shipment. Both packages for the PE3335 are moisture sensitivity Level 3.

Level 3 Caution Label

The caution label should contain the following information for Level 3 devices:

1. Calculated shelf life in sealed bag: 12 months at $<40^{\circ}\text{C}$ and $<90\%$ relative humidity (RH)
2. Peak package body temperature is 225°C .
3. After bag is opened, devices that will be subjected to reflow solder or other high temperature process must
 - a) Be mounted within 168 hours of factory conditions $<30^{\circ}\text{C}/60\%$ RH, **or**
 - b) Be stored at $<10\%$ RH
4. Devices require bake, before mounting, if:
 - a) Humidity Indicator Card is $> 10\%$ when read at $23 \pm 5^{\circ}\text{C}$
 - b) 3a or 3b are not met
5. If baking is required, devices may be baked for 48 hours at $125 \pm 5/-0^{\circ}\text{C}$

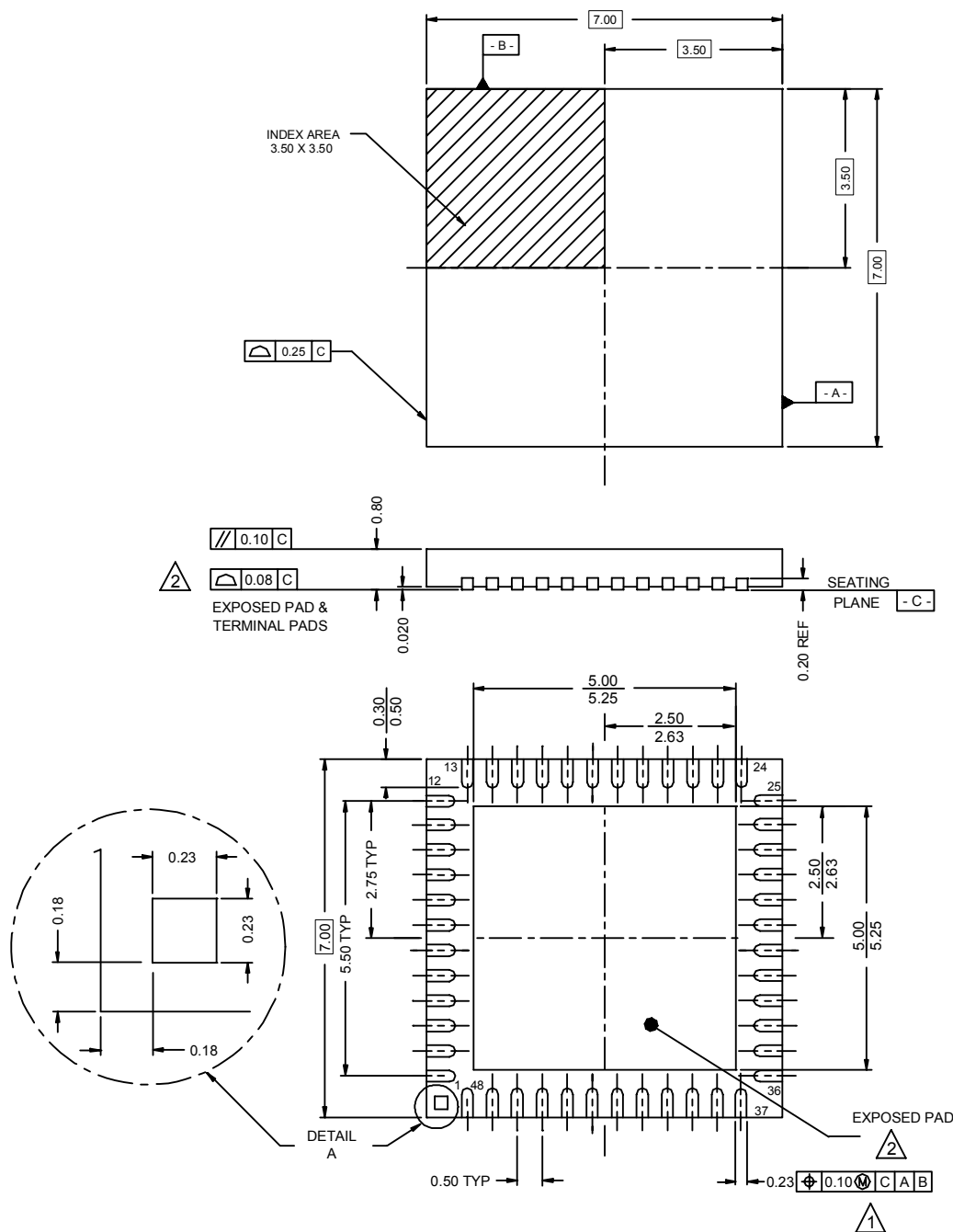
Note: If device containers cannot be subjected to high temperature or shorter bake times are desired, reference IPC/JEDEC-J-STD-033 for bake procedure.

Level and Body temperature defined by:
IPC/JEDEC-J-STD-020

For Dry Bake Procedures, see:
IPC/JEDEC-J-STD-033

Operator must observe ESD precautions per ESD Control Procedure and Parts Handling and shipping Procedure.

48-lead QFN



1. DIMENSION APPLIES TO METALLIZED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 FROM TERMINAL TIP.
2. COPLANARITY APPLIES TO THE EXPOSED HEAT SINK SLUG AS WELL AS THE TERMINALS.

Figure 7. Package Drawing

44-lead PLCC

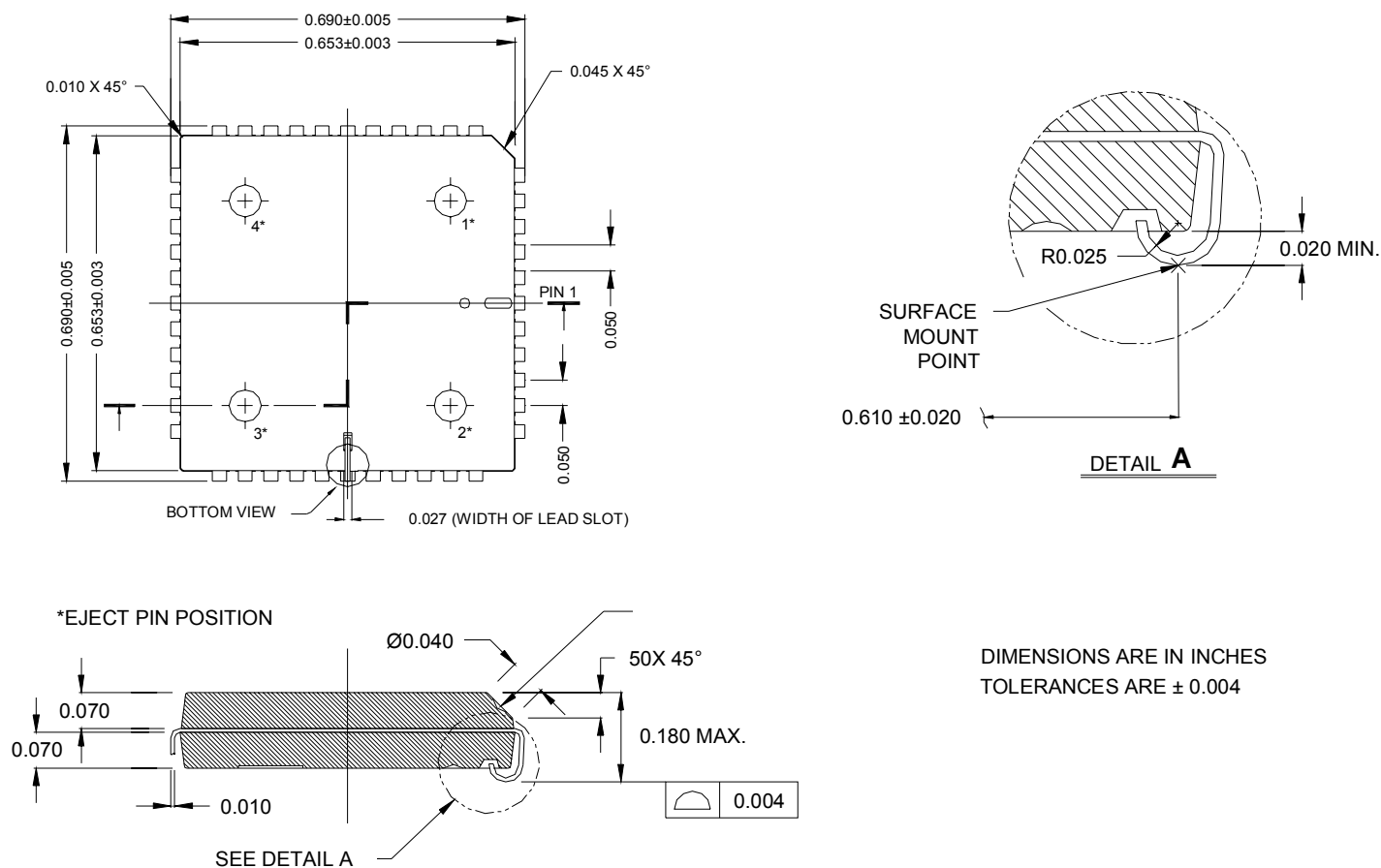


Table 10. Ordering Information

Order Code	Part Marking	Description	Package	Shipping Method
3335-21	PE3335	PE3335-44PLCC-27A	44-lead PLCC	27 units / Tube
3335-22	PE3335	PE3335-44PLCC-500C	44-lead PLCC	500 units / T&R
3335-23	PE3335	PE3335-48QFN 7x7 mm-52A	48-lead QFN	52 units / Tube
3335-24	PE3335	PE3335-48QFN 7x7 mm-2000C	48-lead QFN	2000 units / T&R
3335-00	PE3335EK	PE3335-44PLCC-EVAL KIT	Evaluation Kit	1 / Box
3335-01	PE3335EK	PE3335-48QFN 7x7 mm-EK	Evaluation Kit	1 / Box

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Data Sheet Identification

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